

Attorney's Docket No.: 07977-052001/US3053

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Hisashi Ohtani, et al Art Unit : 1765
Serial No.: 08/690,747 Examiner : Robert Kunemund
Filed : August 1, 1996 Confirmation No. : 1369
Title : METHOD FOR MANUFACTURING SEMICONDUCTOR DEVICE

Commissioner for Patents
Washington, D.C. 20231

AMENDMENT

Sir:

In response to the Official Action dated June 26, 2002,
Paper No. 29, in the above-referenced application, kindly amend
the above-identified application as follows.

In the Claims:

Please amend the claims as follows.

55. A method for manufacturing a semiconductor device
comprising:
forming a semiconductor film comprising silicon over a
substrate;
providing said semiconductor film with a crystallization
promoting material;

CERTIFICATE OF TRANSMISSION BY FACSIMILE

I hereby certify that this correspondence is being transmitted by
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October 28, 2002

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